74VHC595-Q100; 74VHCT595-Q100

8-bit serial-in/serial-out or parallel-out shift register with output latches

Rev. 2 — 25 June 2020

Product data sheet

1. General description

The 74VHC595-Q100; 74VHCT595-Q100 are high-speed Si-gate CMOS devices and are pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7A.

The 74VHC595-Q100; 74VHCT595-Q100 are 8-stage serial shift registers with a storage register and 3-state outputs. The shift registers have separate clocks.

Data is shifted on the positive-going transitions of the shift register clock input (SHCP). The data in each register is transferred to the storage register on a positive-going transition of the storage register clock input (STCP). If both clocks are connected together, the shift register will always be one clock pulse ahead of the storage register.

The shift register has a serial input (DS) and a serial standard output (Q7S) for cascading. It is also provided with asynchronous reset (active LOW) for all 8 shift register stages. The storage register has 8 parallel 3-state bus driver outputs. Data in the storage register appears at the output whenever the output enable input (\overline{OE}) is LOW.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Balanced propagation delays
- All inputs have Schmitt-trigger action
- Inputs accept voltages higher than V_{CC}
- Input levels:
 - For 74VHC595-Q100: CMOS level
 - For 74VHCT595-Q100: TTL level
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pf, R = 0 Ω)
- · Multiple package options
- DHVQFN package with Side-Wettable Flanks enabling Automatic Optical Inspection (AOI) of solder joints

3. Applications

- · Serial-to-parallel data conversion
- Remote control holding register

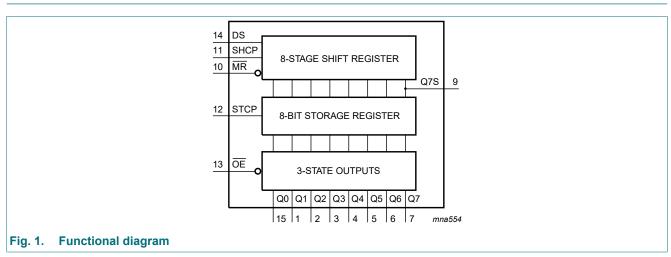


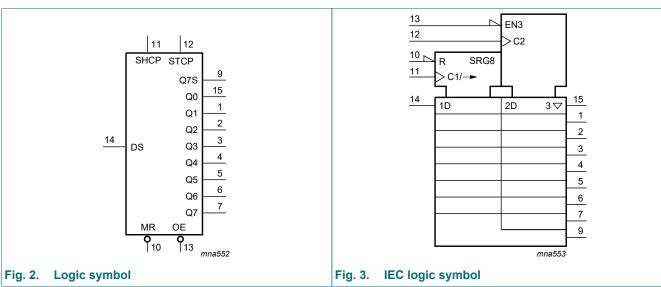
4. Ordering information

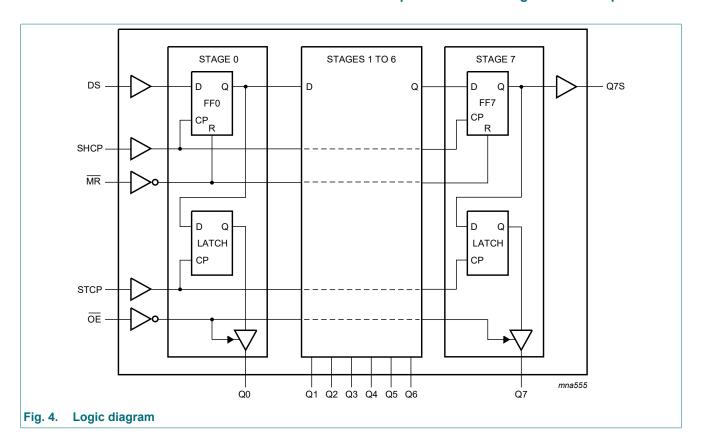
Table 1. Ordering information

| Type number | Package | | | | | | | | | |
|------------------|-------------------|----------|--|----------|--|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | | |
| 74VHC595D-Q100 | -40 °C to +125 °C | SO16 | plastic small outline package; 16 leads; | SOT109-1 | | | | | | |
| 74VHCT595D-Q100 | | | body width 3.9 mm | | | | | | | |
| 74VHC595PW-Q100 | -40 °C to +125 °C | TSSOP16 | plastic thin shrink small outline package; | SOT403-1 | | | | | | |
| 74VHCT595PW-Q100 | | | 16 leads; body width 4.4 mm | | | | | | | |
| 74VHC595BQ-Q100 | -40 °C to +125 °C | DHVQFN16 | plastic dual in-line compatible thermal | SOT763-1 | | | | | | |
| 74VHCT595BQ-Q100 | - | | enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 × 3.5 × 0.85 mm | | | | | | | |

5. Functional diagram

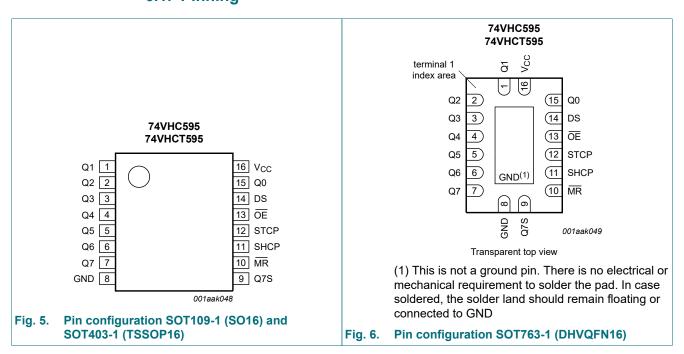






6. Pinning information

6.1. Pinning



6.2. Pin description

Table 2. Pin description

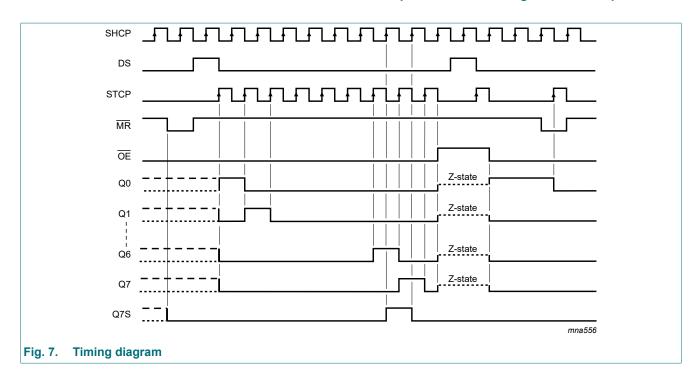
| Symbol | Pin | Description |
|--------------------------------|-------------------------|----------------------------------|
| Q0, Q1, Q2, Q3, Q4, Q5, Q6, Q7 | 15, 1, 2, 3, 4, 5, 6, 7 | parallel data output |
| GND | 8 | ground (0 V) |
| Q7S | 9 | serial data output |
| MR | 10 | master reset (active LOW) |
| SHCP | 11 | shift register clock input |
| STCP | 12 | storage register clock input |
| ŌE | 13 | output enable input (active LOW) |
| DS | 14 | serial data input |
| V _{CC} | 16 | supply voltage |

7. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ state; \ L = LOW \ voltage \ state; \ \uparrow = LOW-to-HIGH \ transition; \ X = don't \ care; \ NC = no \ change; \ Z = high-impedance \ OFF-state.$

| Contro | ol . | | | Input | Outpu | t | Function |
|----------|----------|----|----|-------|-------|-----|--|
| SHCP | STCP | ŌΕ | MR | DS | Q7S | Qn | |
| Χ | Х | L | L | Х | L | NC | a LOW-level on MR only affects the shift registers |
| Χ | 1 | L | L | Х | L | L | empty shift register loaded into storage register |
| Χ | Х | Н | L | Х | L | Z | shift register clear; parallel outputs in high-impedance OFF-state |
| ↑ | Х | L | Н | Н | Q6S | NC | logic HIGH-level shifted into shift register stage 0. Contents of all shift register stages shifted through, e.g. previous state of stage 6 (internal Q6S) appears on the serial output (Q7S). |
| X | 1 | L | Н | Х | NC | QnS | contents of shift register stages (internal QnS) are transferred to the storage register and parallel output stages |
| ↑ | ↑ | L | Н | Х | Q6S | QnS | contents of shift register shifted through; previous contents of the shift register is transferred to the storage register and the parallel output stages |



8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| VI | input voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < -0.5 V [1] | -20 | - | mA |
| I _{OK} | output clamping current | $V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1] | -20 | +20 | mA |
| Io | output current | $V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$ | -25 | +25 | mA |
| I _{CC} | supply current | | - | +75 | mA |
| I _{GND} | ground current | | -75 | - | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ [2] | - | 500 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

^[2] For SOT109-1 (SO16) package: P_{tot} derates linearly with 12.4 mW/K above 110 °C. For SOT403-1 (TSSOP16) package: P_{tot} derates linearly with 8.5 mW/K above 91 °C. For SOT763-1 (DHVQFN16) package: P_{tot} derates linearly with 11.2 mW/K above 106 °C.

9. Recommended operating conditions

Table 5. Operating conditions

| Symbol | Parameter | Conditions | 74V | HC595-0 | 2100 | 74VH | Unit | | |
|------------------|-------------------------------------|----------------------------------|-----|---------|-----------------|------|------|-----------------|------|
| | | | Min | Тур | Max | Min | Тур | Max | |
| V _{CC} | supply voltage | | 2.0 | 5.0 | 5.5 | 4.5 | 5.0 | 5.5 | V |
| VI | input voltage | | 0 | - | 5.5 | 0 | - | 5.5 | V |
| Vo | output voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| Δt/ΔV | input transition rise and fall rate | V _{CC} = 3.0 V to 3.6 V | - | - | 100 | - | - | - | ns/V |
| | | V _{CC} = 4.5 V to 5.5 V | - | - | 20 | - | - | 20 | ns/V |

10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | 25 °C | ; | -40 °C to | o +85 °C | -40 °C to | +125 °C | Unit |
|-----------------|--------------------------|---|------|-------|-------|-----------|----------|-----------|---------|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| 74VHC5 | 95-Q100 | | • | | | | , | | | |
| V_{IH} | HIGH-level | V _{CC} = 2.0 V | 1.5 | - | - | 1.5 | - | 1.5 | - | V |
| | input voltage | V _{CC} = 3.0 V | 2.1 | - | - | 2.1 | - | 2.1 | - | V |
| | | V _{CC} = 5.5 V | 3.85 | - | - | 3.85 | - | 3.85 | - | V |
| V_{IL} | LOW-level | V _{CC} = 2.0 V | - | - | 0.5 | - | 0.5 | - | 0.5 | V |
| | input voltage | V _{CC} = 3.0 V | - | - | 0.9 | - | 0.9 | - | 0.9 | V |
| | | V _{CC} = 5.5 V | - | - | 1.65 | - | 1.65 | - | 1.65 | V |
| V _{OH} | HIGH-level | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | output voltage | $I_O = -50 \mu A; V_{CC} = 2.0 V$ | 1.9 | 2.0 | - | 1.9 | - | 1.9 | - | V |
| | | I _O = -50 μA; V _{CC} = 3.0 V | 2.9 | 3.0 | - | 2.9 | - | 2.9 | - | V |
| | | I _O = -50 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I_{O} = -4.0 mA; V_{CC} = 3.0 V | 2.58 | - | - | 2.48 | - | 2.40 | - | V |
| | | I_{O} = -8.0 mA; V_{CC} = 4.5 V | 3.94 | - | - | 3.80 | - | 3.70 | - | V |
| V_{OL} | LOW-level | V _I = V _{IH} or V _{IL} | | | | | | | | |
| | output voltage | $I_{O} = 50 \mu A; V_{CC} = 2.0 V$ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | $I_{O} = 50 \mu A; V_{CC} = 3.0 V$ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | $I_{O} = 50 \mu A; V_{CC} = 4.5 V$ | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I_{O} = 4.0 mA; V_{CC} = 3.0 V | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| | | $I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$ | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| l _l | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μΑ |
| I _{OZ} | OFF-state output current | $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5$ V | - | - | ±0.25 | - | ±2.5 | - | ±10 | μΑ |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$ | - | - | 4.0 | - | 40 | - | 80 | μΑ |
| Cı | input capacitance | | - | 3 | 10 | - | 10 | - | 10 | pF |

| Symbol | Parameter | Conditions | | 25 °C | ; | -40 °C t | o +85 °C | -40 °C to | +125 °C | Unit |
|------------------|---------------------------|--|------|-------|-------|----------|----------|-----------|---------|------|
| | | | Min | Тур | Max | Min | Max | Min | Max | |
| 74VHCT | 595-Q100 | | | ' | | | | <u>'</u> | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | 2.0 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | - | 0.8 | - | 0.8 | - | 0.8 | V |
| V _{OH} | HIGH-level | $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$ | | | | | | | | |
| | output voltage | Ι _Ο = -50 μΑ | 4.4 | 4.5 | - | 4.4 | - | 4.4 | - | V |
| | | I _O = -8.0 mA | 3.94 | - | - | 3.80 | - | 3.70 | - | V |
| V _{OL} | LOW-level | $V_I = V_{IH}$ or V_{IL} ; $V_{CC} = 4.5 \text{ V}$ | | | | | | | | |
| | output voltage | I _O = 50 μA | - | 0 | 0.1 | - | 0.1 | - | 0.1 | V |
| | | I _O = 8.0 mA | - | - | 0.36 | - | 0.44 | - | 0.55 | V |
| l _l | input leakage current | V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V | - | - | 0.1 | - | 1.0 | - | 2.0 | μA |
| l _{OZ} | OFF-state output current | $V_I = V_{IH}$ or V_{IL} ; $V_O = V_{CC}$ or GND; $V_{CC} = 5.5$ V | - | - | ±0.25 | - | ±2.5 | - | ±10 | μΑ |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$ | - | - | 4.0 | - | 40 | - | 80 | μΑ |
| ΔI _{CC} | additional supply current | per input pin; $V_I = V_{CC} - 2.1 \text{ V}$; other inputs at V_{CC} or GND; $I_O = 0 \text{ A}$; $V_{CC} = 4.5 \text{ V}$ to 5.5 V | - | - | 1.35 | - | 1.5 | - | 1.5 | mA |
| Cı | input capacitance | | - | 3 | 10 | - | 10 | - | 10 | pF |

11. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 13.

| Symbol | Parameter | Conditions | | | 25 °C | | -40 °C t | o +85 °C | -40 °C to | +125 °C | Unit |
|------------------|--------------|----------------------------------|-----|-----|--------|------|----------|----------|-----------|---------|------|
| | | | | Min | Typ[1] | Max | Min | Max | Min | Max | 1 |
| 74VHC5 | 95-Q100 | | | | | | | | | ' | |
| t _{pd} | propagation | SHCP to Q7S; see Fig. 8 | [2] | | | | | | | | |
| | delay | V _{CC} = 3.0 V to 3.6 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 5.7 | 13.0 | 1.0 | 15.0 | 1.0 | 16.5 | ns |
| | | C _L = 50 pF | | - | 7.7 | 16.5 | 1.0 | 18.5 | 1.0 | 20.1 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 4.0 | 8.2 | 1.0 | 9.4 | 1.0 | 10.5 | ns |
| | | C _L = 50 pF | | - | 5.4 | 10.0 | 1.0 | 11.4 | 1.0 | 12.5 | ns |
| | | STCP to Qn; see Fig. 9 | [2] | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 5.9 | 11.9 | 1.0 | 13.5 | 1.0 | 15.0 | ns |
| | | C _L = 50 pF | | - | 7.7 | 15.4 | 1.0 | 17.0 | 1.0 | 18.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 4.2 | 7.4 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| | | C _L = 50 pF | | - | 5.5 | 9.0 | 1.0 | 10.5 | 1.0 | 11.5 | ns |
| | | MR to Q7S; see Fig. 11 | [3] | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 5.9 | 12.8 | 1.0 | 13.7 | 1.0 | 15.0 | ns |
| | | C _L = 50 pF | | - | 7.4 | 16.3 | 1.0 | 17.2 | 1.0 | 18.7 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 4.4 | 8.0 | 1.0 | 9.1 | 1.0 | 10.0 | ns |
| | | C _L = 50 pF | | - | 5.6 | 10.0 | 1.0 | 11.1 | 1.0 | 12.0 | ns |
| t _{en} | enable time | OE to Qn; see Fig. 12 | [4] | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 5.6 | 11.5 | 1.0 | 13.5 | 1.0 | 15.0 | ns |
| | | C _L = 50 pF | | - | 7.4 | 15.0 | 1.0 | 17.0 | 1.0 | 18.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 4.0 | 8.6 | 1.0 | 10.0 | 1.0 | 11.0 | ns |
| | | C _L = 50 pF | | - | 5.3 | 10.6 | 1.0 | 12.0 | 1.0 | 13.0 | ns |
| t _{dis} | disable time | OE to Qn; see Fig. 12 | [5] | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 5.4 | 11.0 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| | | C _L = 50 pF | | - | 8.7 | 15.7 | 1.0 | 16.2 | 1.0 | 17.5 | ns |
| | | V _{CC} = 4.5 V to 5.5 V | | | | | | | | | |
| | | C _L = 15 pF | | - | 3.8 | 8.0 | 1.0 | 9.5 | 1.0 | 10.5 | ns |
| | | C _L = 50 pF | | - | 5.8 | 10.3 | 1.0 | 11.0 | 1.0 | 12.0 | ns |

| Symbol | Parameter | Conditions | | 25 °C | | -40 °C t | o +85 °C | -40 °C to | o +125 °C | Unit |
|------------------|-------------------------------------|--|-----|--------|-----|----------|----------|-----------|-----------|------|
| | | | Min | Typ[1] | Max | Min | Max | Min | Max | |
| f _{max} | maximum frequency | SHCP or STCP; see Fig. 8 and Fig. 9 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 80 | 125 | - | 60 | - | 40 | - | MHz |
| | | V _{CC} = 4.5 V to 5.5 V | 130 | 170 | - | 110 | - | 90 | - | MHz |
| t _W | pulse width | SHCP HIGH or LOW; see Fig. 8 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | STCP HIGH or LOW; see Fig. 9 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | MR LOW; see Fig. 11 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| t _{su} | set-up time | DS to SHCP; see Fig. 10 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 3.5 | - | - | 3.5 | - | 3.5 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 3.0 | - | - | 3.0 | - | 3.0 | - | ns |
| | | SHCP to STCP; see Fig. 9 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 8.5 | - | - | 8.5 | - | 8.5 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| t _h | hold time | DS to SHCP; see Fig. 10 | | | | | | | | |
| | | V _{CC} = 3.0 V to 3.6 V | 1.5 | - | - | 1.5 | - | 1.5 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 2.0 | - | - | 2.0 | - | 2.0 | - | ns |
| t _{rec} | recovery | MR to SHCP; see Fig. 11 | | | | | | | | |
| | time | V _{CC} = 3.0 V to 3.6 V | 3.0 | - | - | 3.0 | - | 3.0 | - | ns |
| | | V _{CC} = 4.5 V to 5.5 V | 2.5 | - | - | 2.5 | - | 2.5 | - | ns |
| C _{PD} | power dissipation capacitance | f_i = 1 MHz; [6] V_I = GND to V_{CC} ; all 9 outputs switching | - | 180 | - | - | - | - | - | pF |

| Symbol | Parameter | Conditions | | | 25 °C | | -40 °C to | o +85 °C | -40 °C to +125 °C Min Max 1.0 10.0 1.0 12.0 1.0 9.5 1.0 11.5 1.0 10.5 1.0 12.5 | | Unit |
|------------------|-------------------------------------|---|-----|-----|--------|------|-----------|----------|---|------|------|
| | | | | Min | Typ[1] | Max | Min | Max | Min | Max | |
| 74VHCT | 595-Q100; V _C | _{CC} = 4.5 V to 5.5 V | | | | | | , | | | • |
| t _{pd} | propagation | SHCP to Q7S; see Fig. 8 | [2] | | | | | | | | |
| | delay | C _L = 15 pF | | - | 3.8 | 8.2 | 1.0 | 9.0 | 1.0 | 10.0 | ns |
| | | C _L = 50 pF | | - | 5.2 | 10.0 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| | | STCP to Qn; see Fig. 9 | [2] | | | | | | | | |
| | | C _L = 15 pF | | - | 4.0 | 7.4 | 1.0 | 8.5 | 1.0 | 9.5 | ns |
| | | C _L = 50 pF | | - | 5.3 | 9.0 | 1.0 | 10.5 | 1.0 | 11.5 | ns |
| | | MR to Q7S; see Fig. 11 | [3] | | | | | | | | |
| | | C _L = 15 pF | | - | 4.6 | 8.2 | 1.0 | 9.5 | 1.0 | 10.5 | ns |
| | | C _L = 50 pF | | - | 5.8 | 10.5 | 1.0 | 11.5 | 1.0 | 12.5 | ns |
| t _{en} | enable time | OE to Qn; see Fig. 12 | [4] | | | | | | | | |
| | | C _L = 15 pF | | - | 4.8 | 9.0 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| | | C _L = 50 pF | | - | 6.2 | 11.6 | 1.0 | 13.0 | 1.0 | 14.5 | ns |
| t _{dis} | disable time | OE to Qn; see Fig. 12 | [5] | | | | | | | | |
| | | C _L = 15 pF | | - | 3.6 | 6.9 | 1.0 | 8.0 | 1.0 | 9.0 | ns |
| | | C _L = 50 pF | | - | 5.8 | 10.3 | 1.0 | 11.0 | 1.0 | 12.0 | ns |
| f _{max} | maximum frequency | SHCP and STCP; see Fig. 8 and Fig. 9 | | 130 | 170 | - | 110 | - | 90 | - | MHz |
| t _W | pulse width | SHCP HIGH or LOW; see Fig. 8 | | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | STCP HIGH or LOW; see Fig. 9 | | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| | | MR LOW; see Fig. 11 | | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| t _{su} | set-up time | DS to SHCP; see Fig. 10 | | 3.0 | - | - | 3.0 | - | 3.0 | - | ns |
| | | SHCP to STCP; see Fig. 9 | | 5.0 | - | - | 5.0 | - | 5.0 | - | ns |
| t _h | hold time | DS to SHCP; see Fig. 10 | | 2.0 | - | - | 2.0 | - | 2.0 | - | ns |
| t _{rec} | recovery time | MR to SHCP; see Fig. 11 | | 3.0 | - | - | 3.0 | - | 3.0 | - | ns |
| C _{PD} | power dissipation capacitance | $\begin{split} f_i &= 1 \text{ MHz;} \\ V_I &= \text{GND to V}_{CC}; \\ \text{all 9 outputs switching} \end{split}$ | [6] | - | 190 | - | - | - | - | - | pF |

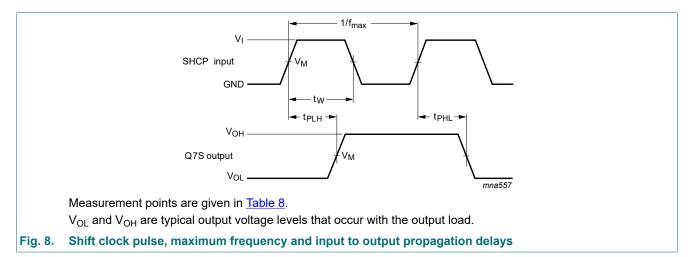
- Typical values are measured at nominal supply voltage.
- t_{pd} is the same as t_{PHL} and t_{PLH} . [2]
- [3]
- t_{pd} is the same as t_{PHL} only. t_{en} is the same as t_{PZL} and t_{PZH} . [4]
- ten is the same as tp_{ZL} and tp_{ZH}.
 t_{dis} is the same as t_{PLZ} and t_{PHZ}.
 C_{PD} is used to determine the dynamic power dissipation (P_D in μW).
 P_D = C_{PD} x V_{CC}² x f_i + Σ(C_L x V_{CC}² x f_o) where:
 f_i = input frequency in MHz;

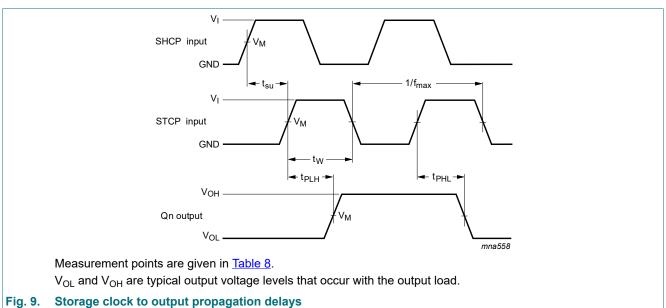
$$\begin{split} &f_o = \text{output frequency in MHz;} \\ &\Sigma(C_L \ x \ V_{CC} \ ^2 \ x \ f_o) = \text{sum of outputs;} \end{split}$$

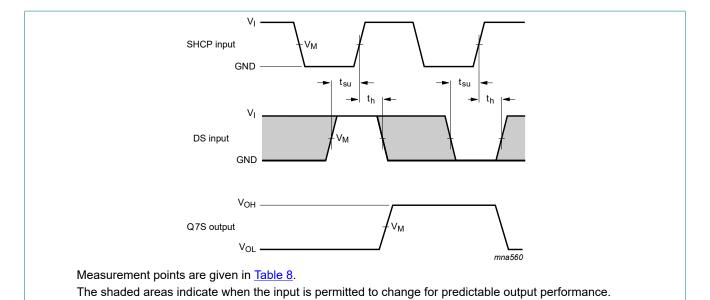
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V.

11.1. Waveforms and test circuit







V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 10. Data set-up and hold times

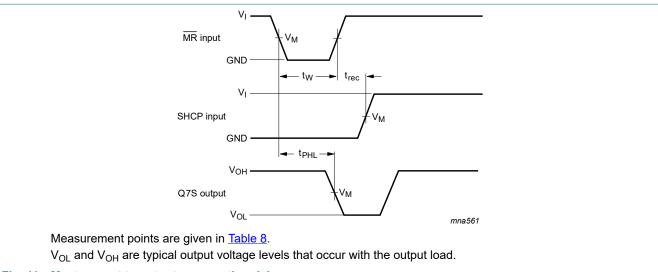


Fig. 11. Master reset to output propagation delays

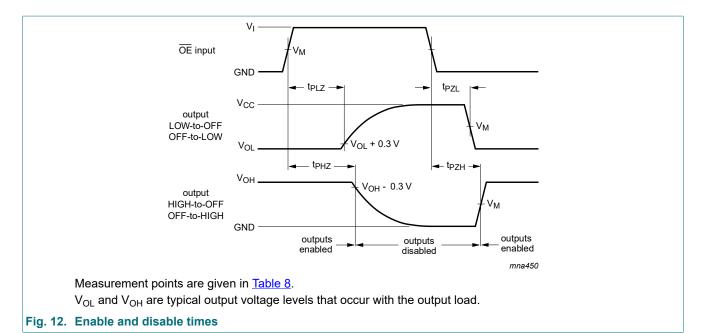
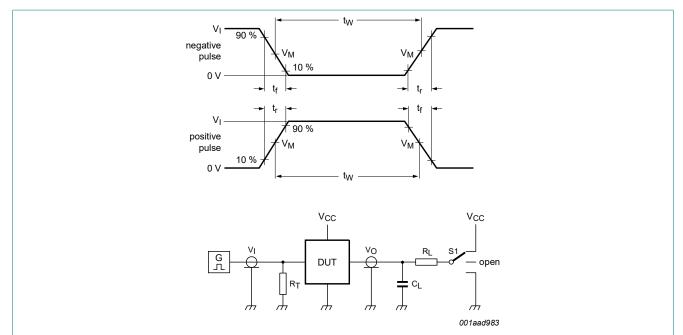


Table 8. Measurement points

| Туре | Input | Output |
|----------------|--------------------|--------------------|
| | V _M | V _M |
| 74VHC595-Q100 | 0.5V _{CC} | 0.5V _{CC} |
| 74VHCT595-Q100 | 1.5 V | 0.5V _{CC} |



Test data is given in Table 9.

Definitions for test circuit:

 C_L = load capacitance including jig and probe capacitance.

R_L = load resistance.

 R_T = termination resistance should be equal to the output impedance Z_o of the pulse generator.

S1 = test selection switch.

Fig. 13. Test circuit for measuring switching times

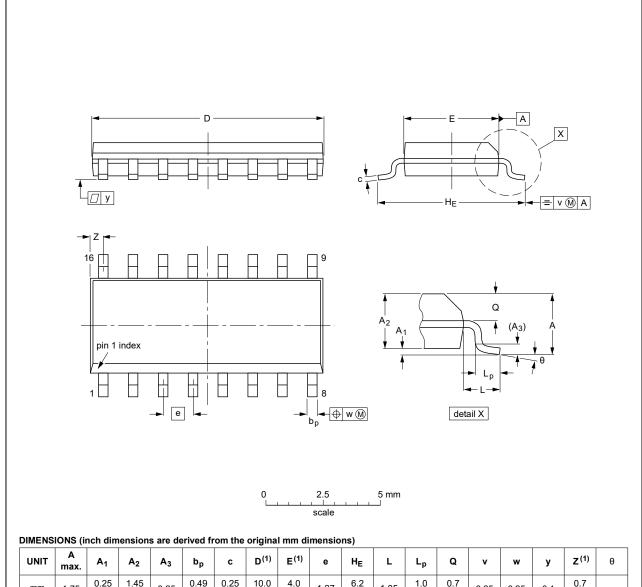
Table 9. Test data

| Туре | Input | | Load | | S1 position | | | |
|----------------|-----------------|---------------------------------|----------------|-------|-------------------------------------|-------------------------------------|-------------------------------------|--|
| | V _I | t _r , t _f | C _L | R_L | t _{PHL} , t _{PLH} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} | |
| 74VHC595-Q100 | V _{CC} | ≤ 3.0 ns | 15 pF, 50 pF | 1 kΩ | open | GND | V _{CC} | |
| 74VHCT595-Q100 | 3.0 V | ≤ 3.0 ns | 15 pF, 50 pF | 1 kΩ | open | GND | V _{CC} | |

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | е | HE | L | Lp | Q | v | w | у | Z ⁽¹⁾ | θ |
|--------|-----------|----------------|----------------|----------------|--------------|------------------|------------------|------------------|------|----------------|-------|----------------|----------------|------|------|-------|------------------|----|
| mm | 1.75 | 0.25 0.10 | 1.45 1.25 | 0.25 | 0.49 0.36 | 0.25 0.19 | 10.0 9.8 | 4.0 3.8 | 1.27 | 6.2 5.8 | 1.05 | 1.0 0.4 | 0.7 0.6 | 0.25 | 0.25 | 0.1 | 0.7 0.3 | 8° |
| inches | 0.069 | 0.010 0.004 | 0.057 0.049 | 0.01 | l | 0.0100 0.0075 | 0.39 0.38 | 0.16 0.15 | 0.05 | 0.244 0.228 | 0.041 | 0.039 0.016 | 0.028 0.020 | 0.01 | 0.01 | 0.004 | 0.028 0.012 | 0° |

Note

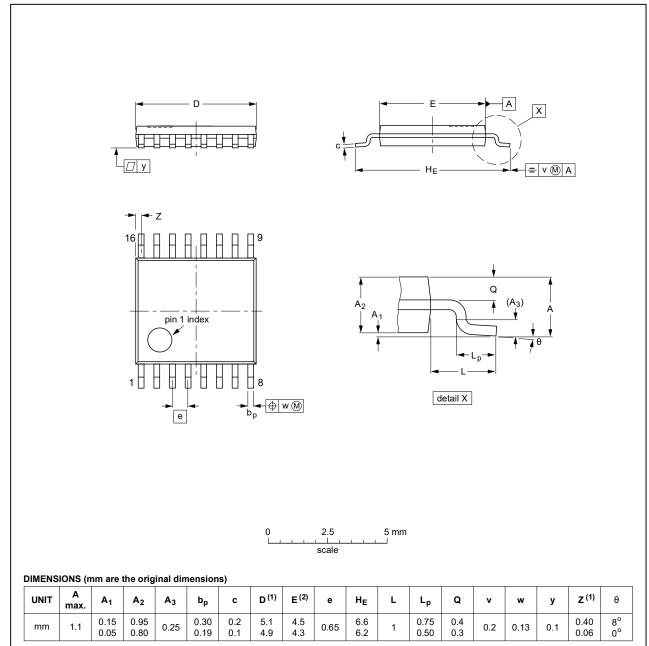
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | |
|----------|--------|--------|----------|------------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | 1330E DATE | |
| SOT109-1 | 076E07 | MS-012 | | | | 99-12-27 03-02-19 | |

Fig. 14. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | EUROPEAN | ISSUE DATE | | | |
|----------|-----|--------|----------|------------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | | PROJECTION | ISSUE DATE | |
| SOT403-1 | | MO-153 | | | | 99-12-27 03-02-18 | |

Fig. 15. Package outline SOT403-1 (TSSOP16)

DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

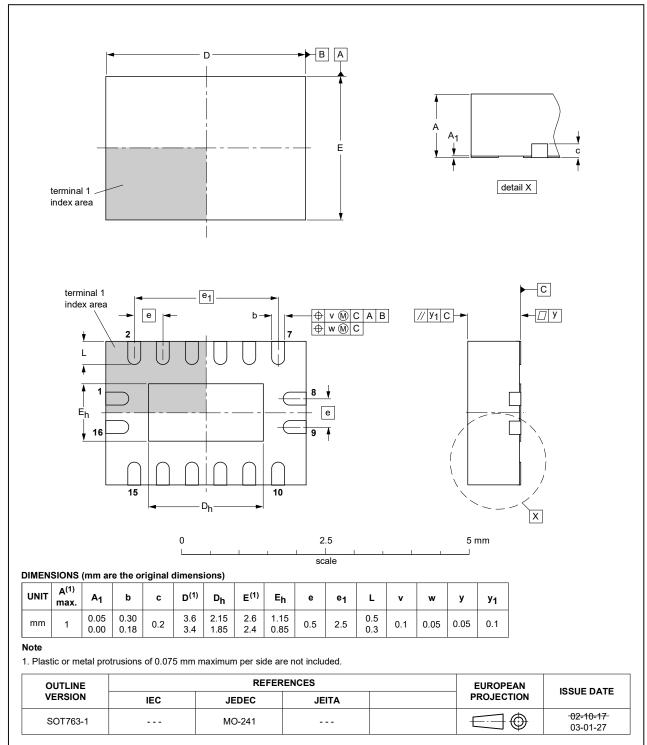


Fig. 16. Package outline SOT763-1 (DHVQFN16)

13. Abbreviations

Table 10. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal-Oxide Semiconductor |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| MIL | Military |
| MM | Machine Model |
| TTL | Transistor-Transistor Logic |

14. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|------------------------|---|--|----------------------|------------------------|--|--|
| 74VHC_VHCT595_Q100 v.2 | 20200625 | Product data sheet | - | 74VHC_VHCT595_Q100 v.1 | | |
| Modifications: | The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. | | | | | |
| | Section 2 update | | | | | |
| | <u>Fig. 7</u>: updated (| SHCP waveform adde | d). | | | |
| | <u>Table 4</u>: Derating | g values for P _{tot} total po | wer dissipation upda | ated. | | |
| | • <u>Table 6</u> : Condition | ons for I _{OZ} corrected. | | | | |
| 74VHC_VHCT595_Q100 v.1 | 20131115 | Product data sheet | - | - | | |

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|--------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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